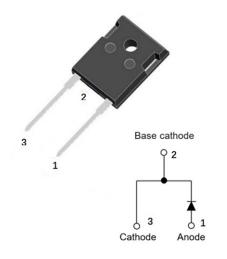


YJD112060NYG4

RoHS COMPLIANT

Silicon Carbide Schottky Diode

V _{RRM}	1200V
I _{F(135°C)}	66A
Q _c	332nC



Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

- Package: TO-247AC
- Terminals: Tin plated leads
- Polarity: As marked

■Maximum Ratings (T_C=25[°]C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Device marking code			D112060NYG4
Reverse voltage (Repetitive peak) @ T _j =25°C	V _{RRM}	v	1200
Reverse voltage (Surge peak) @ T _j =25°C	V _{RSM}	V	1200
Reverse voltage (DC) @ T _j =25°C	V _{DC}	V	1200
Continuous forward current @ T _c =25°C			142
Continuous forward current @ T _c =135°C	I _F	A	66
Continuous forward current @ T _c =141°C			60
Non-repetitive peak forward surge current @ $T_c=25^{\circ}C$, tp=10ms, Half Sine Wave	I _{FSM}	А	390
Power Dissipation@ T _c =25°C	Ρτοτ	w	500
Power Dissipation@ T _c =110°C	Гтот		216
i²t Value@ T _c =25°C ,tp=10ms	∫ i²dt	A ² S	760.5
Operating junction and Storage temperature range	T _j ,T _{stg}	°C	-55 to +175

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Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.	
E-market and the second	VF	V	I _F =60A, T _j =25°C	1.40	1.60	
Forward voltage drop			I _F =60A, Tj=175°C	1.95	-	
Deveree europt		I _R μA	V _R =1200V, T _j =25°C	0.5	25	
Reverse current	IR		V _R =1200V, T _j =175°C	10	-	
Total capacitive charge	Qc	nC	$V_{\text{R}}\text{=}800\text{V},T_{j}\text{=}25^{\circ}\text{C}$, $Q_{\text{C}}\text{=}\int_{0}^{\text{VR}}\text{C}(\text{V})\text{dV}$	332	-	
			V _R =0V, f=1MHZ	4703	-	
Total capacitance	C pF	C pF	pF	V _R =400V, f=1MHZ	310	-
			V _R =800V, f=1MHZ	230	-	
Capacitance stored energy	Ec	μJ	V _R =800V	86	-	

■Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{_{ ext{ hetaJ-C}}}$	°C /W	0.30

■Typical Characteristics

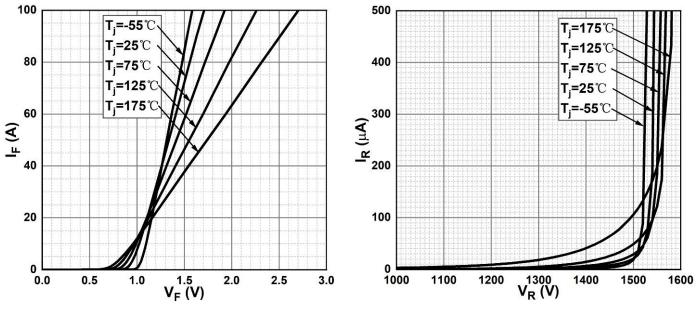
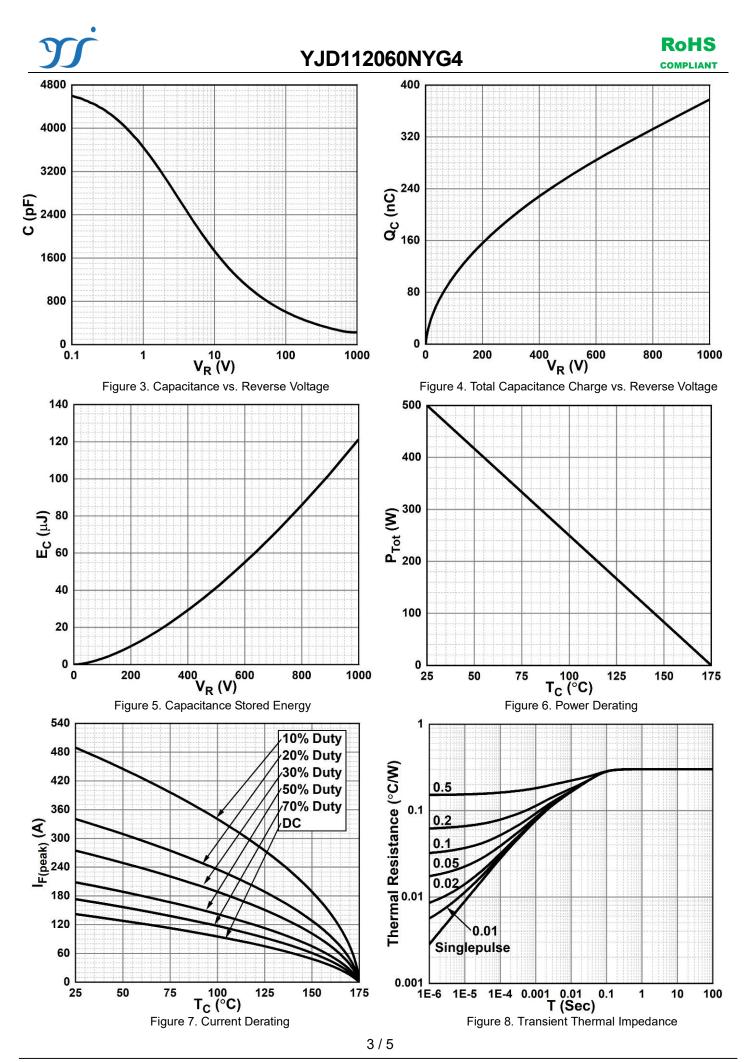


Figure 1. Forward Characteristics

Figure 2. Reverse Characteristics

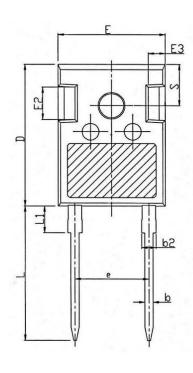


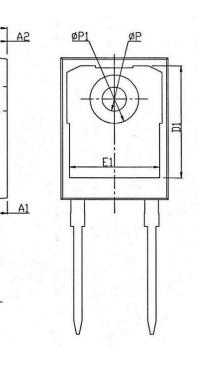


Outline Dimensions

TO-247AC

C





TO-247AC				
Dim	Min	Max		
Α	4.80	5.20		
A1	2.21	2.61		
A2	1.85	2.15		
b	1.11	1.36		
b2	1.91	2.21		
С	0.51	0.75		
D	20.70	21.30		
D1	16.25	16.85		
Е	15.50	16.10		
E1	13.00	13.60		
E2	4.80	5.20		
E3	2.30	2.70		
е	10.88BSC			
L	19.62	20.22		
L1	-	4.30		
ΦP	3.40	3.80		
ΦP1	-	7.30		
S	6.15BSC			

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